

V_{CES}	650V
I_C	40A
$V_{CE(sat)}$ (Typ.)	1.5V
P_D	227W

●Features

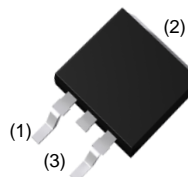
- 1) AEC-Q101 Qualified
- 2) Low Collector - Emitter Saturation Voltage
- 3) Low Switching Loss & Soft Switching
- 4) Built in Very Fast & Soft Recovery FRD
- 5) Pb - free Lead Plating ; RoHS Compliant

●Application

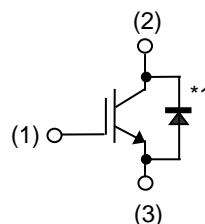
Automotive
On & Off Board Chargers
DC-DC Converters
PFC
Industrial Inverter

●Outline

LPDL (TO-263L)



●Inner Circuit



(1) Gate
(2) Collector
(3) Emitter

*1 Built in FRD

●Packaging Specifications

Type	Packaging	Taping
	Reel Size (mm)	330
	Tape Width (mm)	24
	Basic Ordering Unit (pcs)	1,000
	Packing Code	TL
	Marking	RGW80NL65D

●Absolute Maximum Ratings (at $T_C = 25^\circ\text{C}$ unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V_{CES}	650	V
Gate - Emitter Voltage		V_{GES}	± 30	V
Collector Current	$T_C = 25^\circ\text{C}$	I_C	83	A
	$T_C = 100^\circ\text{C}$	I_C	50	A
Pulsed Collector Current		I_{CP}^{*1}	160	A
Diode Forward Current	$T_C = 25^\circ\text{C}$	I_F	43	A
	$T_C = 100^\circ\text{C}$	I_F	25	A
Diode Pulsed Forward Current		I_{FP}^{*1}	160	A
Power Dissipation	$T_C = 25^\circ\text{C}$	P_D	227	W
	$T_C = 100^\circ\text{C}$	P_D	114	W
Operating Junction Temperature		T_j	-40 to +175	$^\circ\text{C}$
Storage Temperature		T_{stg}	-55 to +175	$^\circ\text{C}$

*1 Pulse width limited by T_{jmax} .

● Thermal Resistance

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal Resistance IGBT Junction - Case	$R_{\theta(j-c)}$	-	-	0.66	°C/W
Thermal Resistance Diode Junction - Case	$R_{\theta(j-c)}$	-	-	1.55	°C/W

● IGBT Electrical Characteristics (at $T_j = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Collector - Emitter Breakdown Voltage	BV_{CES}	$I_C = 10\mu\text{A}$, $V_{GE} = 0\text{V}$	650	-	-	V
Collector Cut - off Current	I_{CES}	$V_{CE} = 650\text{V}$, $V_{GE} = 0\text{V}$	-	-	10	μA
Gate - Emitter Leakage Current	I_{GES}	$V_{GE} = \pm 30\text{V}$, $V_{CE} = 0\text{V}$	-	-	± 200	nA
Gate - Emitter Threshold Voltage	$V_{GE(th)}$	$V_{CE} = 5\text{V}$, $I_C = 26.0\text{mA}$	5.0	6.0	7.0	V
Collector - Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 40\text{A}$, $V_{GE} = 15\text{V}$, $T_j = 25^\circ\text{C}$	-	1.5	1.9	V
		$T_j = 175^\circ\text{C}$	-	1.85	-	

●IGBT Electrical Characteristics (at $T_j = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Input Capacitance	C_{ies}	$V_{CE} = 30\text{V}$,	-	3320	-	pF
Output Capacitance	C_{oes}	$V_{GE} = 0\text{V}$,	-	83	-	
Reverse transfer Capacitance	C_{res}	$f = 1\text{MHz}$	-	60	-	
Total Gate Charge	Q_g	$V_{CE} = 400\text{V}$,	-	110	-	nC
Gate - Emitter Charge	Q_{ge}	$I_C = 40\text{A}$,	-	23	-	
Gate - Collector Charge	Q_{gc}	$V_{GE} = 15\text{V}$	-	41	-	
Turn - on Delay Time	$t_{d(on)}$	$I_C = 20\text{A}$, $V_{CC} = 400\text{V}$, $V_{GE} = 15\text{V}$, $R_G = 10\Omega$, $T_j = 25^\circ\text{C}$	-	42	-	ns
Rise Time	t_r		-	11	-	
Turn - off Delay Time	$t_{d(off)}$		-	148	-	
Fall Time	t_f		-	37	-	
Turn - on Switching Loss	E_{on}	Inductive Load * E_{on} include diode reverse recovery	-	0.24	-	mJ
Turn - off Switching Loss	E_{off}		-	0.33	-	
Turn - on Delay Time	$t_{d(on)}$	$I_C = 20\text{A}$, $V_{CC} = 400\text{V}$, $V_{GE} = 15\text{V}$, $R_G = 10\Omega$, $T_j = 175^\circ\text{C}$	-	39	-	ns
Rise Time	t_r		-	12	-	
Turn - off Delay Time	$t_{d(off)}$		-	179	-	
Fall Time	t_f		-	75	-	
Turn - on Switching Loss	E_{on}	Inductive Load * E_{on} include diode reverse recovery	-	0.27	-	mJ
Turn - off Switching Loss	E_{off}		-	0.51	-	
Reverse Bias Safe Operating Area	RBSOA	$I_C = 160\text{A}$, $V_{CC} = 520\text{V}$, $V_P = 650\text{V}$, $V_{GE} = 15\text{V}$, $R_G = 100\Omega$, $T_j = 175^\circ\text{C}$	FULL SQUARE			-

●FRD Electrical Characteristics (at $T_j = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Diode Forward Voltage	V_F	$I_F = 20\text{A}$, $T_j = 25^\circ\text{C}$ $T_j = 175^\circ\text{C}$	- -	1.45 1.55	1.9 -	V
Diode Reverse Recovery Time	t_{rr}	$I_F = 20\text{A}$, $V_{CC} = 400\text{V}$, $di_F/dt = 200\text{A}/\mu\text{s}$, $T_j = 25^\circ\text{C}$	-	92	-	ns
Diode Peak Reverse Recovery Current	I_{rr}		-	6.7	-	A
Diode Reverse Recovery Charge	Q_{rr}		-	0.34	-	μC
Diode Reverse Recovery Energy	E_{rr}		-	14.1	-	μJ
Diode Reverse Recovery Time	t_{rr}	$I_F = 20\text{A}$, $V_{CC} = 400\text{V}$, $di_F/dt = 200\text{A}/\mu\text{s}$, $T_j = 175^\circ\text{C}$	-	123	-	ns
Diode Peak Reverse Recovery Current	I_{rr}		-	7.8	-	A
Diode Reverse Recovery Charge	Q_{rr}		-	0.59	-	μC
Diode Reverse Recovery Energy	E_{rr}		-	30.7	-	μJ

●Electrical Characteristic Curves

Fig.1 Power Dissipation
vs. Case Temperature

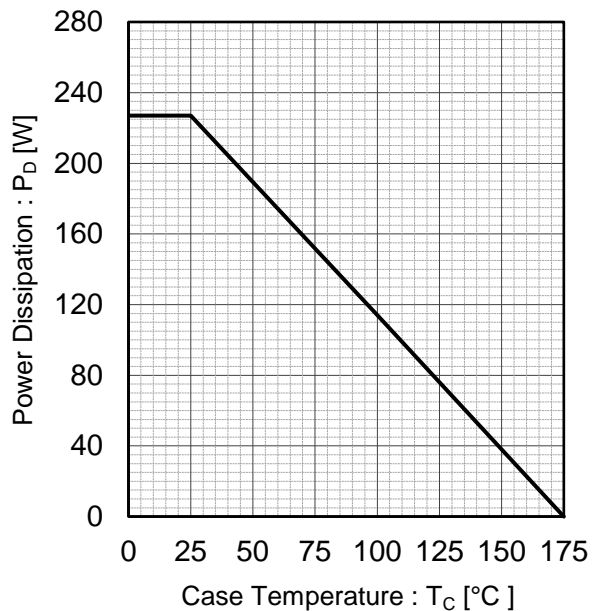


Fig.2 Collector Current
vs. Case Temperature

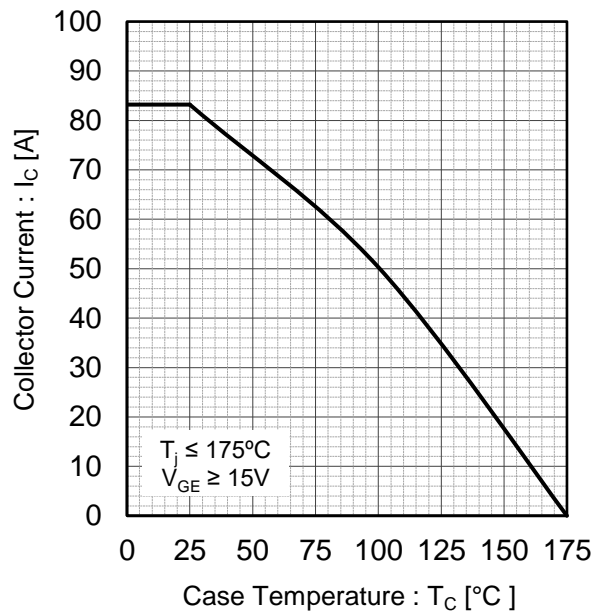


Fig.3 Forward Bias Safe Operating Area

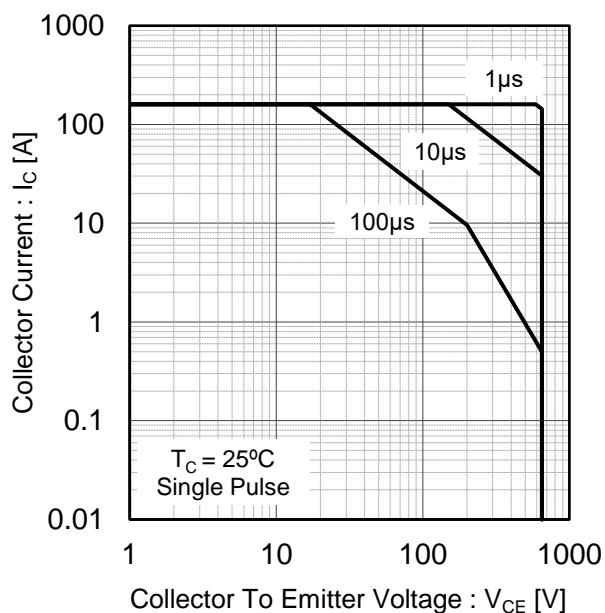
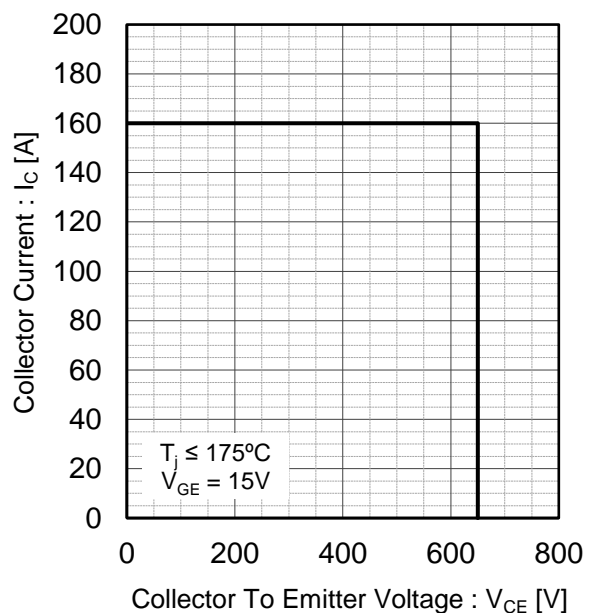


Fig.4 Reverse Bias Safe Operating Area



●Electrical Characteristic Curves

Fig.5 Typical Output Characteristics

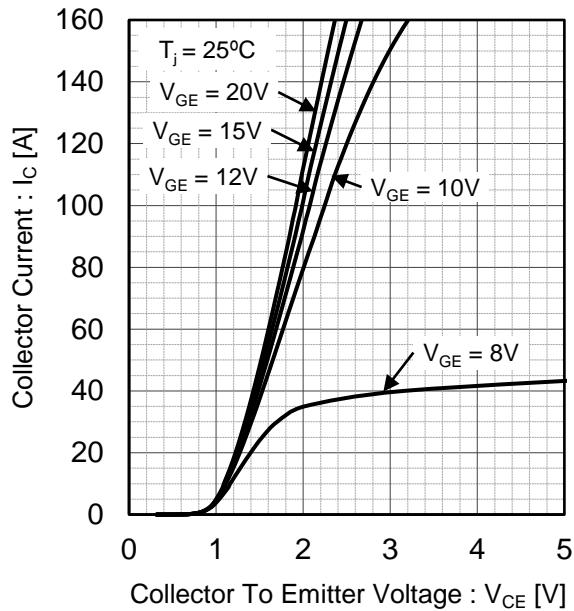


Fig.6 Typical Output Characteristics

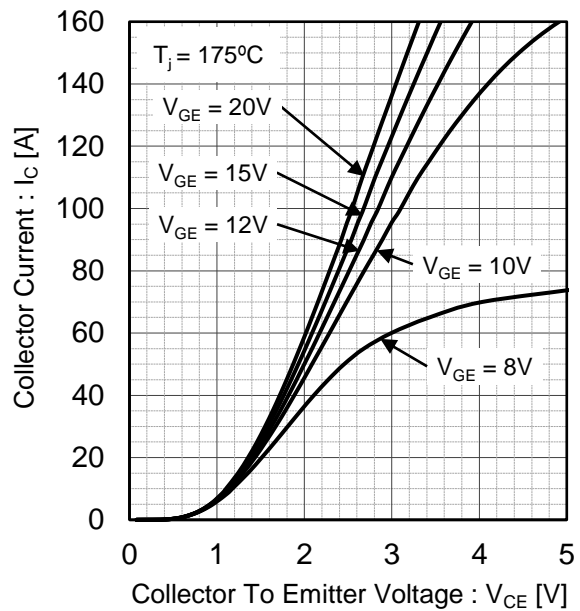


Fig.7 Typical Transfer Characteristics

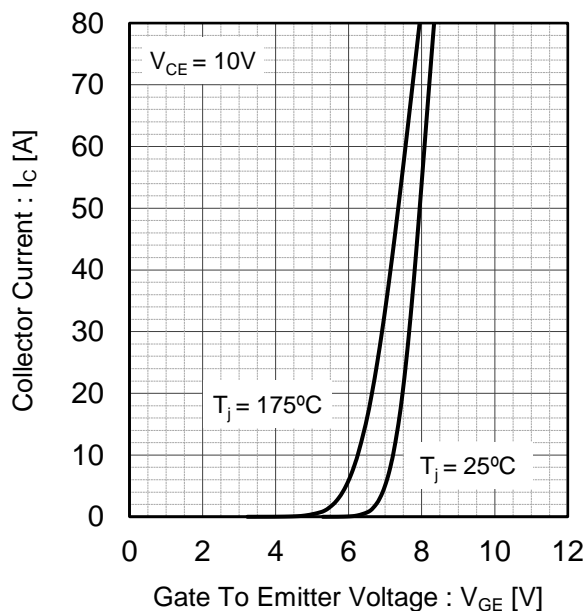
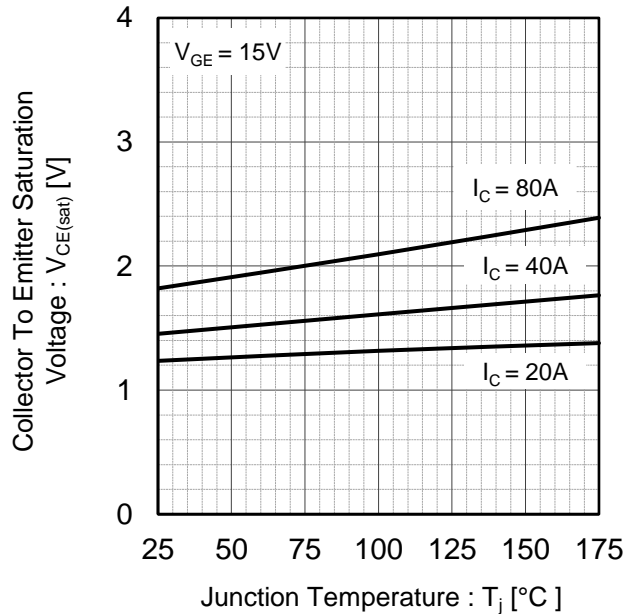


Fig.8 Typical Collector to Emitter Saturation Voltage vs. Junction Temperature



●Electrical Characteristic Curves

Fig.9 Typical Collector to Emitter Saturation Voltage vs. Gate to Emitter Voltage

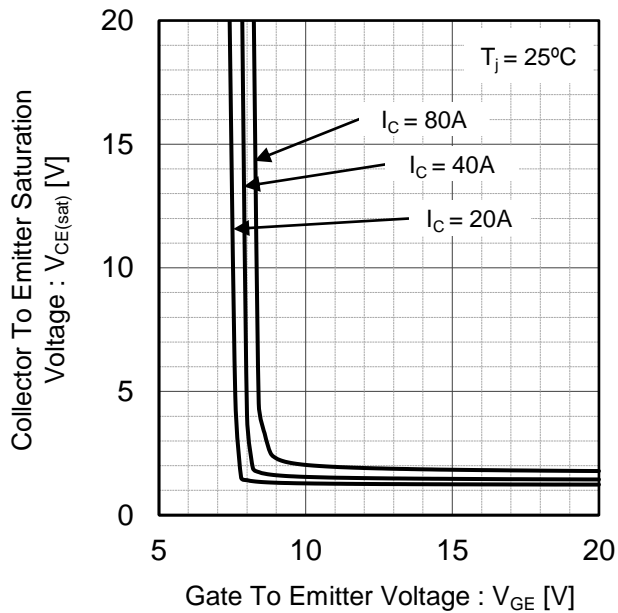


Fig.10 Typical Collector to Emitter Saturation Voltage vs. Gate to Emitter Voltage

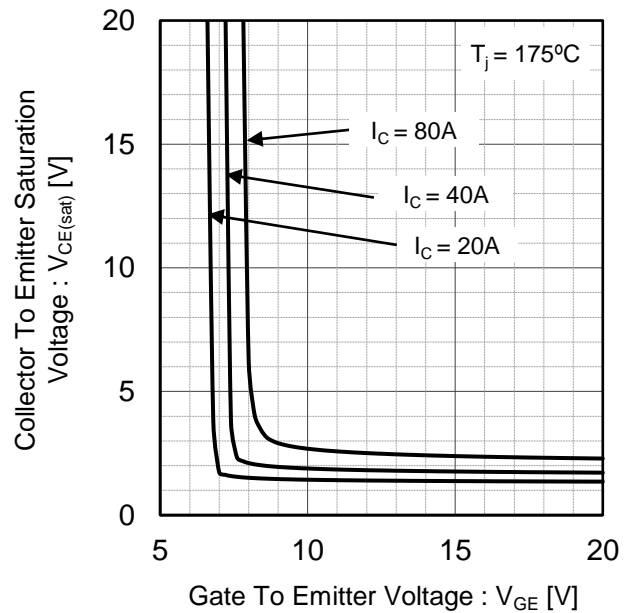


Fig.11 Typical Capacitance vs. Collector to Emitter Voltage

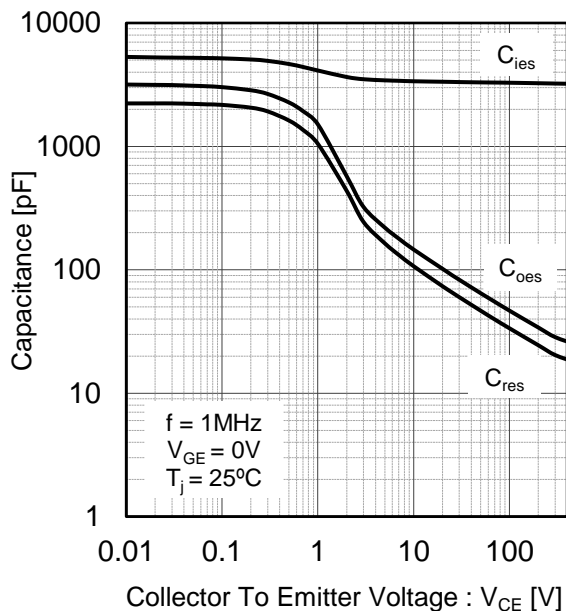
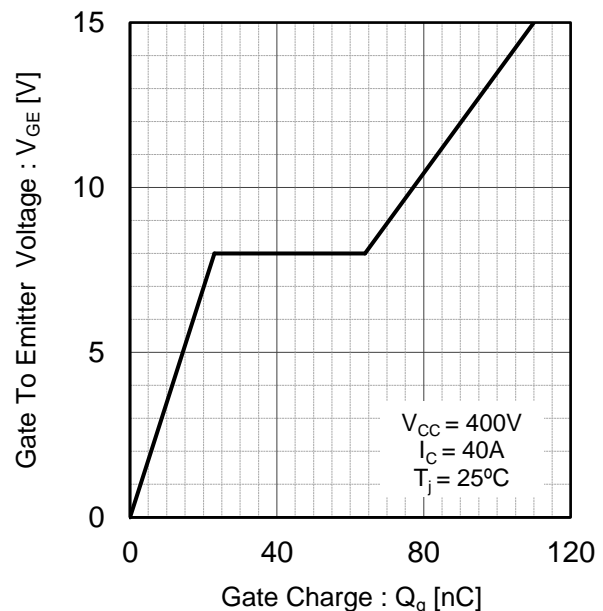


Fig.12 Typical Gate Charge



●Electrical Characteristic Curves

Fig.13 Typical Switching Time
vs. Collector Current

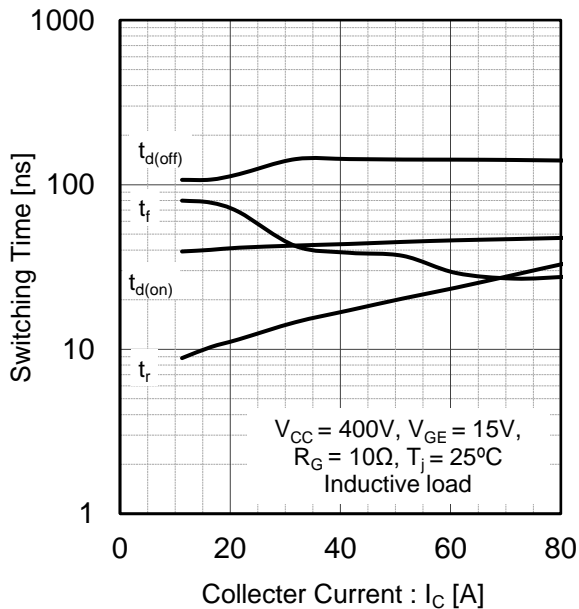


Fig.14 Typical Switching Time
vs. Gate Resistance

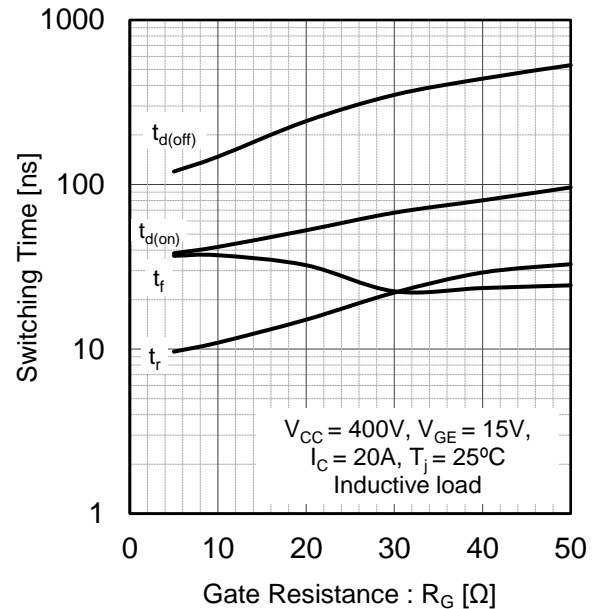


Fig.15 Typical Switching Energy Losses
vs. Collector Current

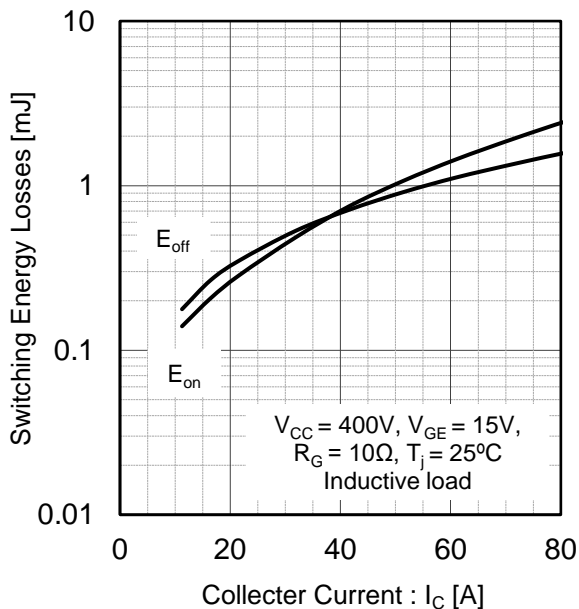
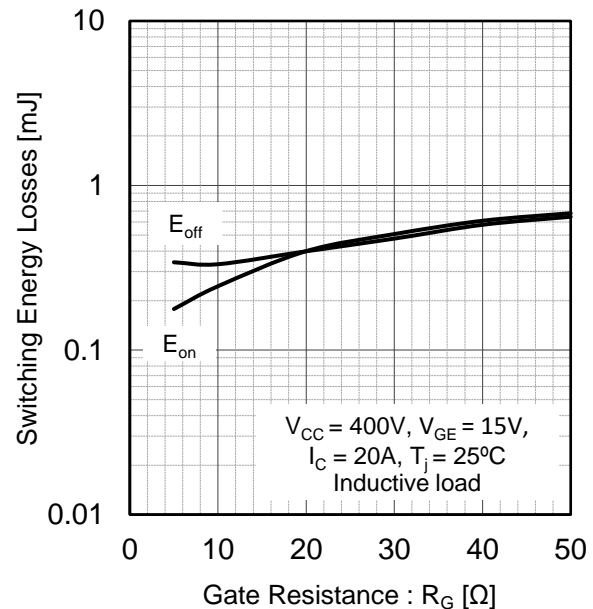


Fig.16 Typical Switching Energy Losses
vs. Gate Resistance



●Electrical Characteristic Curves

Fig.17 Typical Switching Time
vs. Collector Current

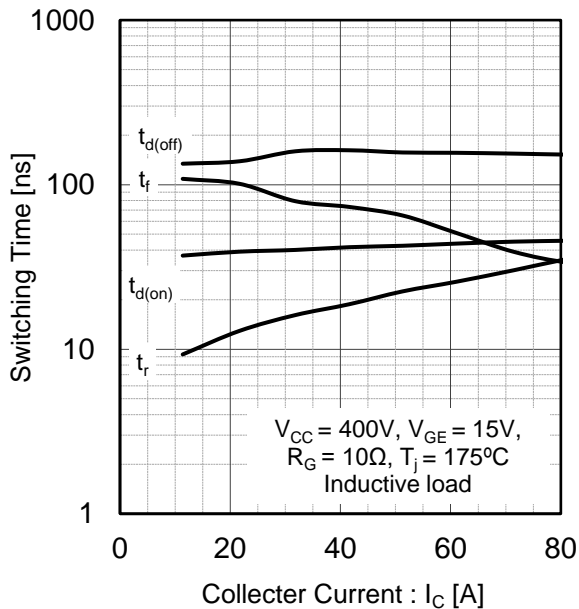


Fig.18 Typical Switching Time
vs. Gate Resistance

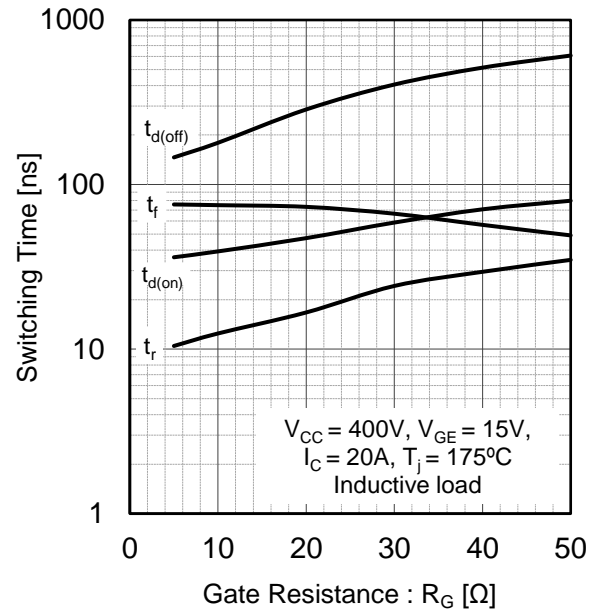


Fig.19 Typical Switching Energy Losses
vs. Collector Current

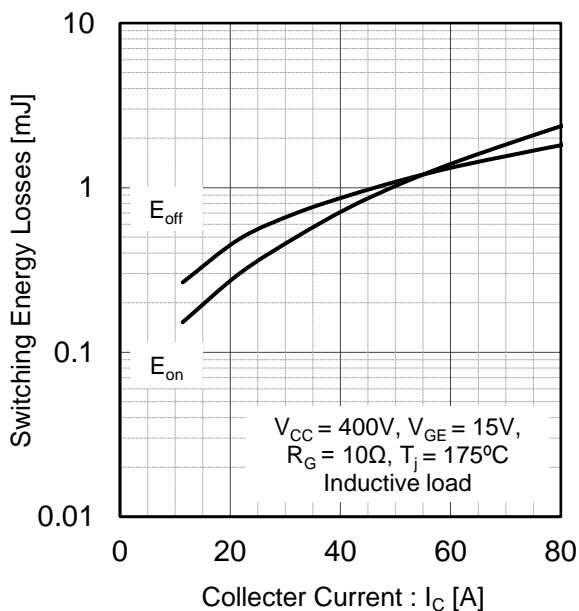
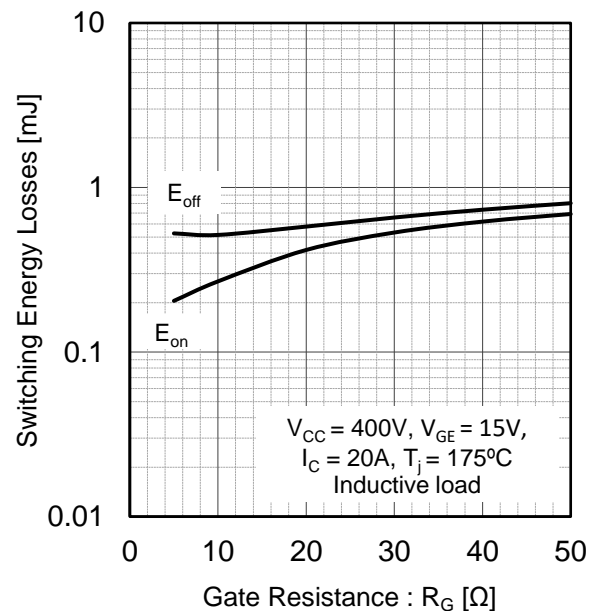


Fig.20 Typical Switching Energy Losses
vs. Gate Resistance



●Electrical Characteristic Curves

Fig.21 Typical Diode Forward Current vs. Forward Voltage

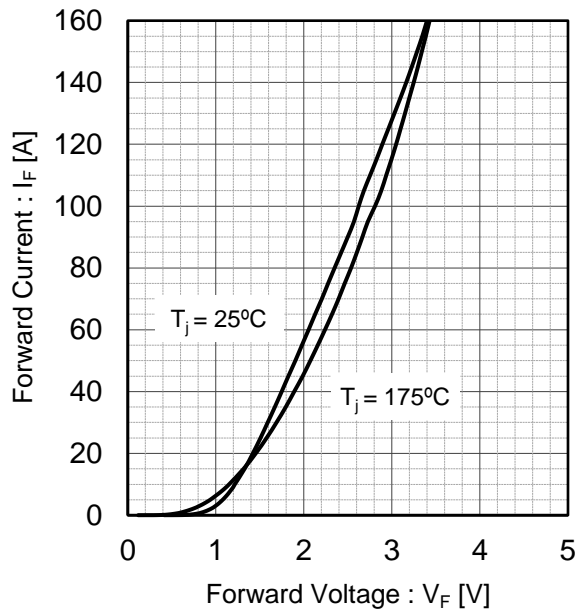


Fig.22 Typical Diode Reverse Recovery Time vs. Forward Current

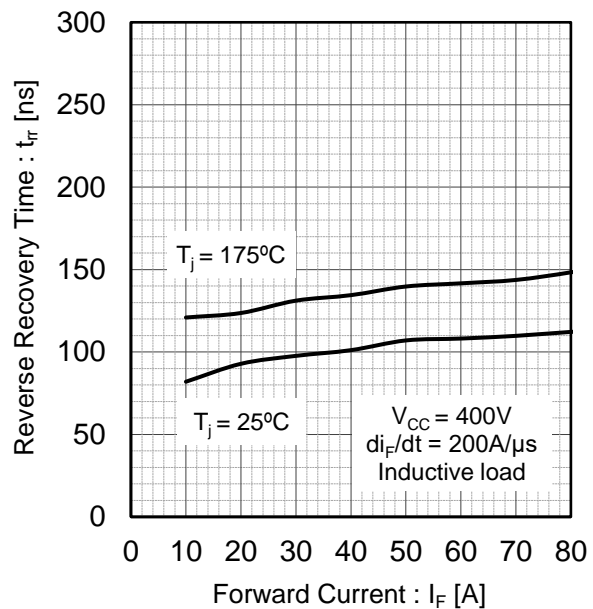


Fig.23 Typical Diode Reverse Recovery Current vs. Forward Current

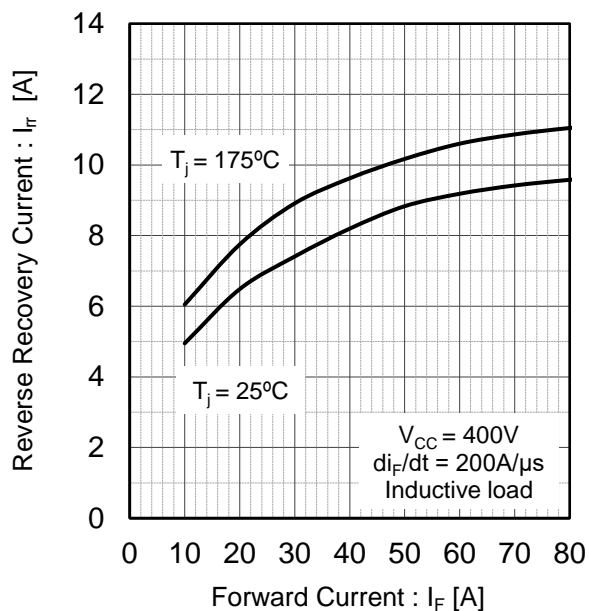
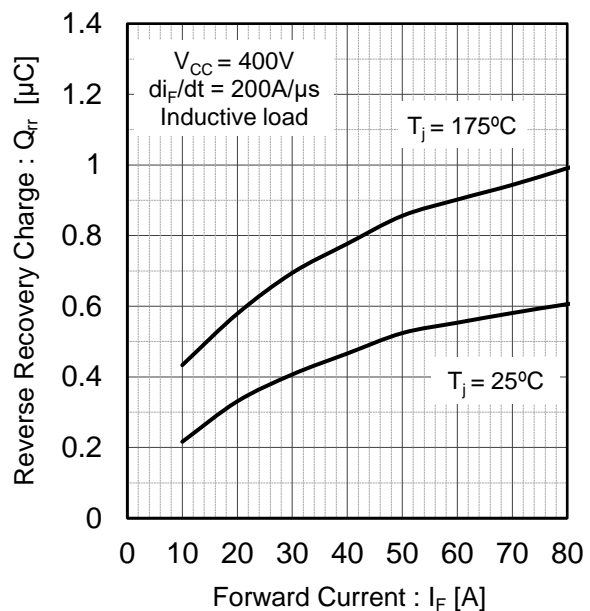


Fig.24 Typical Diode Reverse Recovery Charge vs. Forward Current



●Electrical Characteristic Curves

Fig.25 Typical IGBT Transient Thermal Impedance

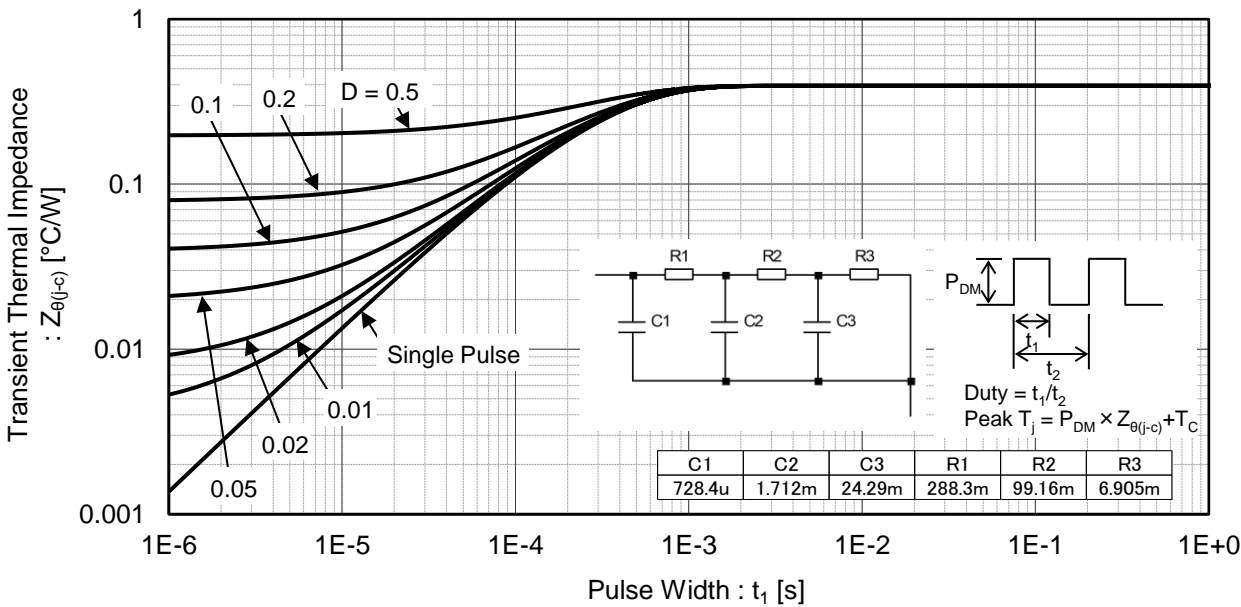
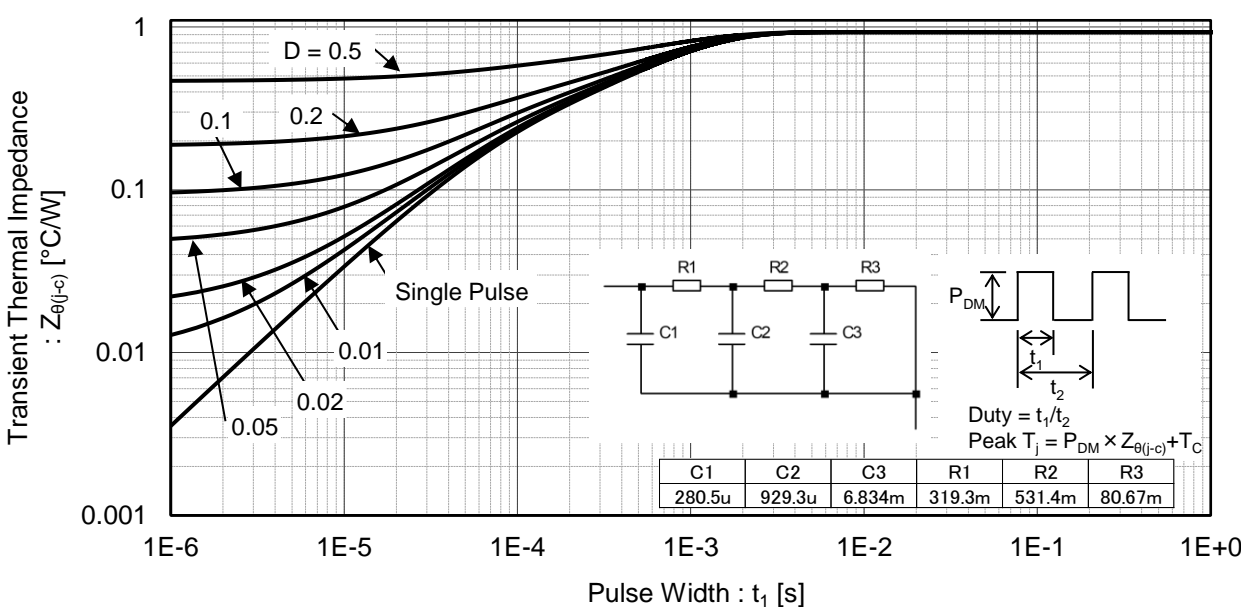


Fig.26 Typical Diode Transient Thermal Impedance



●Inductive Load Switching Circuit and Waveform

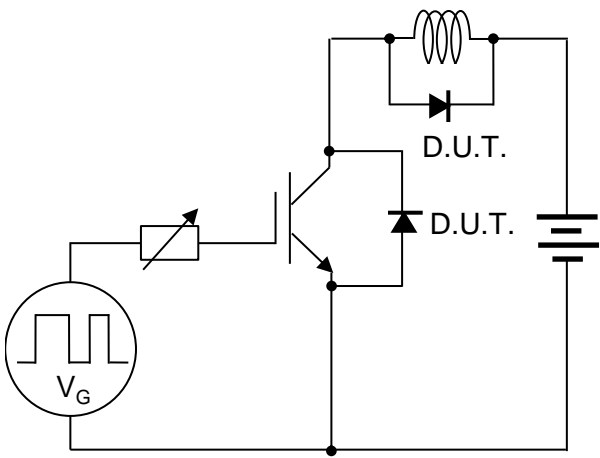


Fig.27 Inductive Load Circuit

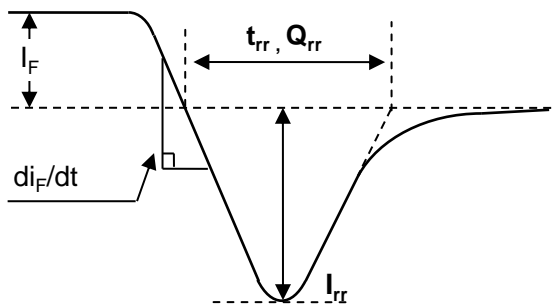


Fig.29 Diode Reverse Recovery Waveform

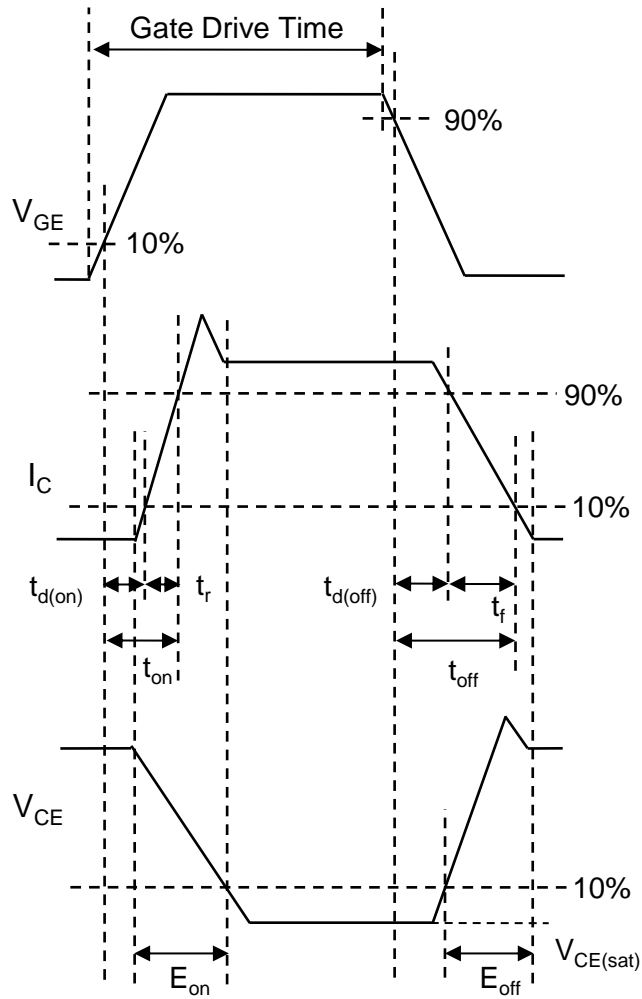


Fig.28 Inductive Load Waveform

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